PIP3206-R

DESCRIPTION

Monolithic single channel high side protected power switch in **TOPFET2** technology assembled in a 5 pin plastic surface mount package.

APPLICATIONS

General controller for driving lamps, motors, solenoids, heaters.

FEATURES

- Vertical power TrenchMOS
- Low on-state resistance
- CMOS logic compatible
- Very low quiescent currentLatched overtemperature
- protection
 Load current limiting at reduced level
- Short circuit load detection
- Overvoltage and undervoltage shutdown with hysteresis
- Diagnostic status indication
- Voltage clamping for turn off of inductive loads
- ESD protection on all pins
- Reverse battery, overvoltage and transient protection

QUICK REFERENCE DATA

SYMBOL	PARAMETER	PARAMETER						
V _{BG}	Continuous off-state supply volta	Continuous off-state supply voltage						
I _L	Continuous load current		10	А				
T _j	Continuous junction temperature	150	°C					
R _{on}	On-state resistance T _j :	= 25°C	14	mΩ				

FUNCTIONAL BLOCK DIAGRAM



PIN CONFIGURATION

3

5

Fig. 2.

2

SYMBOL



PINNING - SOT426

PIN	DESCRIPTION
1	Ground
2	Input
3	(connected to mb)
4	S tatus
5	Load
mb	Battery

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LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{BG}	Continuous off-state supply voltage		0	50	V
IL.	Continuous load current	T _{mb} ≤140°C	-	10	А
P _D	Total power dissipation	T _{mb} ≤25°C	-	115	W
T _{stg}	Storage temperature		-55	175	°C
T _j	Continuous junction temperature ¹		-	150	°C
T_{sold}	Mounting base temperature	during soldering	-	260	°C
	Reverse battery voltages ²				
-V _{BG}	Continuous reverse voltage		-	16	V
-V _{BG}	Peak reverse voltage		-	32	V
	Application information				
R _I , R _S	External resistors ³	to limit input, status currents	3.2	-	kΩ
	Input and status				
I _I , I _S	Continuous currents		-5	5	mA
I _I , I _S	Repetitive peak currents	$\delta \leq 0.1, tp = 300 \; \mu s$	-50	50	mA
	Inductive load clamping	$I_{L} = 10 \text{ A}, V_{BG} = 16 \text{ V}$			
E _{BL}	Non-repetitive clamping energy	$T_j = 150^{\circ}C$ prior to turn-off	-	460	mJ

ESD LIMITING VALUE

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _c	Electrostatic discharge capacitor voltage	Human body model; C = 250 pF; R = 1.5 k Ω	-	2	kV

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
	Thermal resistance ^₄					
R _{th j-mb}	Junction to mounting base	-	-	0.86	1.08	K/W

4 Of the output power MOS transistor.

¹ For normal continuous operation. A higher T_j is allowed as an overload condition but at the threshold $T_{j(TO)}$ the over temperature trip operates to protect the switch.

² Reverse battery voltage is allowed only with external resistors to limit the input and status currents to a safe value. The connected load must limit the reverse load current. The internal ground resistor limits the reverse battery ground current. Power is dissipated and the T_j rating must be observed.

³ To limit currents during reverse battery and transient overvoltages (positive or negative).

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STATIC CHARACTERISTICS

Limits are at -40 $^\circ C \leq T_{mb} \leq$ 150 $^\circ C$ and typicals at T_{mb} = 25 $^\circ C$ unless otherwise stated.

SYMBOL	PARAMETER	CONDITIONS					TYP.	MAX.	UNIT
	Clamping voltages								
V _{BG}	Battery to ground	$I_G = 1 \text{ mA}$	50	55	65	V			
V _{BL}	Battery to load	$I_{L} = I_{G} = 1 \text{ m}$	۱A			50	55	65	V
-V _{LG}	Negative load to ground	$I_{L} = 10 \text{ mA}$				18	23	28	V
-V _{LG}	Negative load voltage ¹	$I_{L} = 20 \text{ A}; t_{p}$	= 300 µ	ιs		20	25	30	V
	Supply voltage	battery to g	round						
V_{BG}	Operating range ²					5.5	-	35	V
	Currents	9 V \leq V _{BG} \leq	16 V						
I _B	Quiescent current ³	$V_{LG} = 0 V$				-	-	20	μA
				T _{mb} =	= 25°C	-	0.1	2	μA
IL.	Off-state load current ⁴	$V_{BL} = V_{BG}$				-	-	20	μΑ
				T _{mb} =	= 25°C	-	0.1	1	μΑ
l _G	Operating current ⁵	$I_L = 0 A$				-	2	4	mA
I _L	Nominal load current ⁶	$V_{BL} = 0.5 V$		T _{mb} =	= 85°C	-	-	-	А
	Resistances	V _{BG}	I _L	t _p ⁷	T_{mb}				
R _{on}	On-state resistance	9 to 35 V	5 A	300 µs	25°C	-	10	14	mΩ
					150°C	-	-	25	mΩ
R _{ON}	On-state resistance	6 V	5 A	300 µs	25°C	-	13	18	mΩ
					150°C	-	-	33	mΩ
R _G	Internal ground resistance	$I_{G} = 10 \text{ mA}$		•		95	150	190	Ω

¹ For a high side switch, the load pin voltage goes negative with respect to ground during the turn-off of an inductive load.

 $^{{\}bf 2}$ On-state resistance is increased if the supply voltage is less than 9 V.

³ This is the continuous current drawn from the supply when the input is low and includes leakage current to the load.

⁴ The measured current is in the load pin only.

⁵ This is the continuous current drawn from the supply with no load connected, but with the input high.

⁶ Defined as in ISO 10483-1. Because of current limiting, this parameter is not applicable.

⁷ The supply and input voltage for the R_{ON} tests are continuous. The specified pulse duration t_p refers only to the applied load current.

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INPUT CHARACTERISTICS

9 V \leq V_{BG} \leq 16 V. Limits are at -40°C \leq T_{mb} \leq 150°C and typicals at T_{mb} = 25 °C unless otherwise stated.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I,	Input current	$V_{IG} = 5 V$	20	90	160	μΑ
V _{IG}	Input clamping voltage	I ₁ = 200 μA	5.5	7	8.5	V
V _{IG(ON)}	Input turn-on threshold voltage		-	2.4	3	V
V _{IG(OFF)}	Input turn-off threshold voltage		1.5	2.1	-	V
ΔV_{IG}	Input turn-on hysteresis		-	0.3	-	V
I _{I(ON)}	Input turn-on current	$V_{IG} = 3 V$	-	-	100	μA
I _{I(OFF)}	Input turn-off current	V _{IG} = 1.5 V	10	-	-	μΑ

STATUS CHARACTERISTICS

The status output is an open drain transistor, and requires an external pull-up circuit to indicate a logic high. Limits are at -40°C $\leq T_{mb} \leq 150$ °C and typicals at $T_{mb} = 25$ °C unless otherwise stated. Refer to TRUTH TABLE.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{SG}	Status clamping voltage	I _s = 100 μA	5.5	7	8.5	V
V _{SG}	Status low voltage	I _s = 100 μA	-	-	1	V
		$T_{mb} = 25^{\circ}C$	-	0.7	0.8	V
I _s	Status leakage current	$V_{SG} = 5 V$	-	-	15	μA
		$T_{mb} = 25^{\circ}C$	-	0.1	1	μA
I _S	Status saturation current ¹	$V_{SG} = 5 V$	2	7	12	mA
	Application information					
Rs	External pull-up resistor		-	47	-	kΩ

¹ In a fault condition with the pull-up resistor short circuited while the status transistor is conducting. This condition should be avoided in order to prevent possible interference with normal operation of the device.

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TOPFET high side switch SMD version

UNDERVOLTAGE & OVERVOLTAGE CHARACTERISTICS

Limits are at -40 $^{\circ}C \leq T_{mb} \leq$ 150 $^{\circ}C$ and typicals at T_{mb} = 25 $^{\circ}C.$ Refer to TRUTH TABLE.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
	Undervoltage					
V _{BG(UV)}	Low supply threshold voltage ¹		2	4.2	5.5	V
$\Delta V_{\text{BG(UV)}}$	Hysteresis		-	0.5	-	V
	Overvoltage					
$\begin{array}{c} V_{BG(OV)} \\ \Delta V_{BG(OV)} \end{array}$	High supply threshold voltage ² Hysteresis		40 -	45 1	50 -	V V

TRUTH TABLE

ABNORMAL CONDITIONS DETECTED					S	LOAD		
INPUT	SUPPLY		LOAD		OUTPUT	STATUS	DESCRIPTION	
UV OV LC SC			ОТ					
L	Х	Х	Х	Х	Х	OFF	Н	off
н	0	0	Х	0	0	ON	Н	on & normal (LC not detected!)
н	1	0	Х	Х	Х	OFF	Н	supply undervoltage lockout
н	0	1	Х	0	0	OFF	Н	supply overvoltage shutdown
н	0	0	0	1	0	ON	L	SC detected (without trip)
н	0	0	Х	X	1	OFF	L	OT shutdown

KEY TO ABBREVIATIONS

- L logic low H logic high X don't care 0 condition not present
- condition present 1

- UV undervoltage OV overvoltage LC low current or open circuit load SC short circuit
- OT overtemperature

¹ Undervoltage sensor causes the device to switch off and reset.

² Overvoltage sensor causes the device to switch off to protect its load.

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OVERLOAD PROTECTION / DETECTION CHARACTERISTICS

6 V \leq V_{BG} \leq 35 V, limits are at -40°C \leq T_{mb} \leq 150°C and typicals at T_{mb} = 25 °C unless otherwise stated. Refer to TRUTH TABLE.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{L(lim)}	Overload protection Load current limiting	$V_{BL} = V_{BG}$ $V_{BG} \ge 9 V$	10	15	21	А
V _{BL(TO)}	Short circuit load detection Battery load threshold voltage ¹	CONDITIONS $V_{BL} = V_{BG}$ $V_{BG} \ge 9 V$ Status indication only $V_{BG} = 16 V$ $V_{BG} = 35 V$		10 20	12 25	> >
T _{j(TO)}	Overtemperature protection Threshold junction temperature ²		150	170	190	°C

SWITCHING CHARACTERISTICS

 T_{mb} = 25 °C, V_{BG} = 13 V, for resistive load R_L = 13 $\Omega.$

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
	During turn-on	from input going high				
t _{d on}	Delay time	to 10% V _L	-	40	60	μs
dV/dt _{on}	Rate of rise of load voltage	30% to 70% V _L	-	0.5	1	V/µs
t _{on}	Total switching time	to 90% V _L	-	180	250	μs
	During turn-off	from input going low				
t _{d off}	Delay time	to 90% V _L	-	50	70	μs
dV/dt _{off}	Rate of fall of load voltage	70% to 30% V _L	-	0.5	1	V/µs
t _{off}	Total switching time	to 10% V _L	-	85	120	μs

CAPACITANCES

 T_{mb} = 25 °C; f = 1 MHz; V_{IG} = 0 V. designed in parameters.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
C _{ig}	Input capacitance	V _{BG} = 13 V	-	15	20	pF
C _{bl}	Output capacitance	$V_{BL} = 13 V$	-	635	900	pF
C _{sg}	Status capacitance	$V_{SG} = 5 V$	-	11	15	pF

¹ The battery to load threshold voltage for short circuit detection is proportional to the battery supply voltage.

² Latched protection. After cooling below the threshold temperature the switch will resume normal operation only after the input has been toggled low.

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TOPFET high side switch SMD version

MECHANICAL DATA



¹ Epoxy meets UL94 V0 at 1/8". Net mass: 1.5 g. For soldering guidelines and SMD footprint design, please refer to Data Handbook SC18.

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DEFINITIONS

DATA SHEET STATUS					
DATA SHEET STATUS ¹	PRODUCT STATUS ²	DEFINITIONS			
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice			
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product			
Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A			

Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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